

## Supporting Information

### **Direct ink writing of high-performance Bi<sub>2</sub>Te<sub>3</sub>-based thermoelectric materials by quasi-inorganic inks and interface engineering**

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In order to gain more insights into the thermal properties of the as-printed samples, we calculated the thermal conductivity according to the relationship:

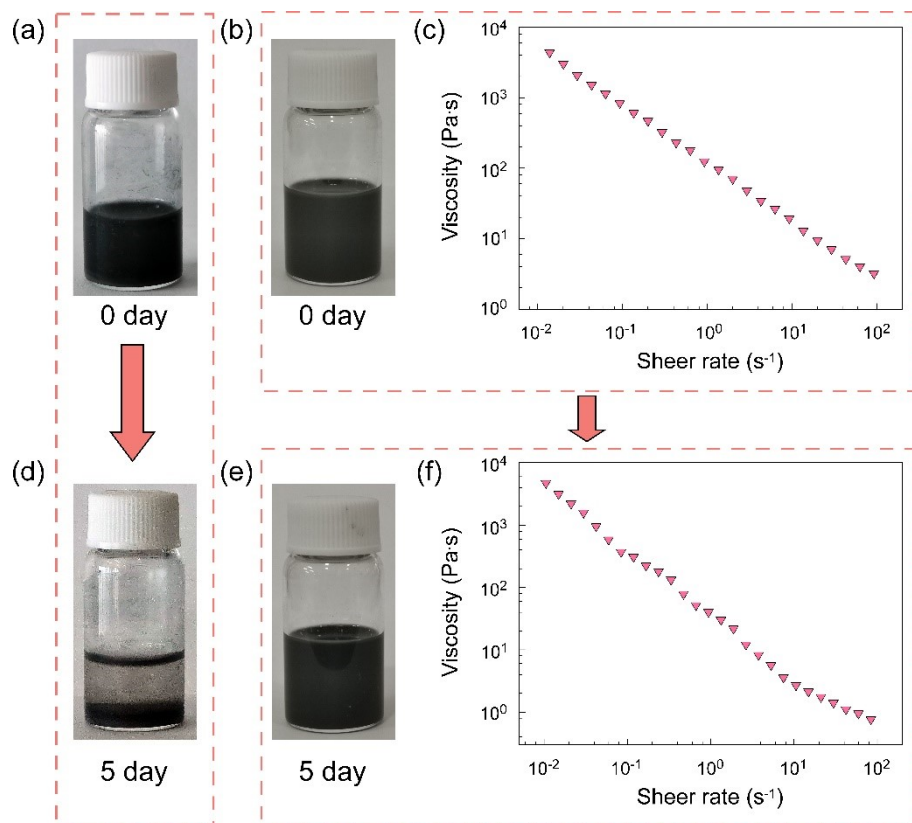
$$\kappa_{tot} = \kappa_{ele} + \kappa_{lat} + \kappa_b \quad \text{\textyen* MERGEFORMAT (1)}$$

where  $\kappa_{tot}$  is the total thermal conductivities,  $\kappa_{lat}$  is the lattice thermal conductivities,  $\kappa_b$  is the bipolar thermal conductivities,  $\kappa_{ele}$  is the electrical thermal conductivities, respectively. Besides,  $\kappa_{ele}$  can be estimated by Wiedemann–Franz law  $\kappa_{ele} = L\sigma T$ , as shown in Fig. S7a and S7d.

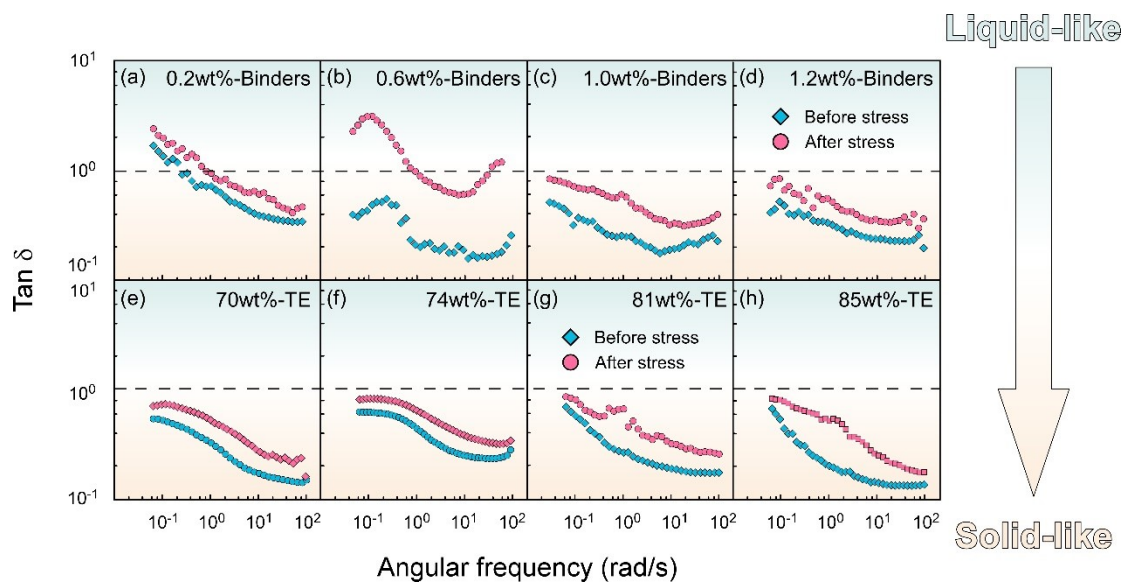
Since lattice vibration dominate the phonon scattering process above Debye temperature, temperature-dependent  $\kappa_{lat}$  can be extrapolated by the following expression [1, 2]:

$$\kappa_{lat} = A + B \cdot T^{-1} \quad \text{\textyen* MERGEFORMAT (2)}$$

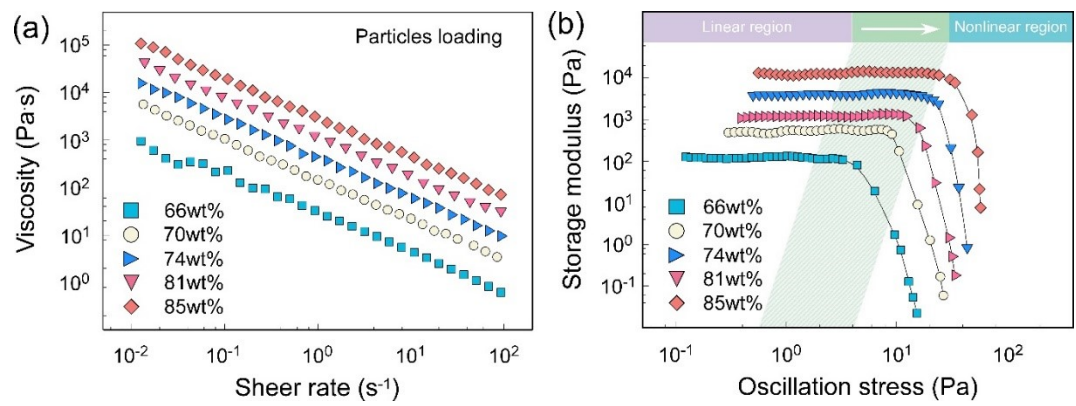
where  $A$  and  $B$  are the fitting parameters. We can achieve the fitted values of  $A$  and  $B$ , according to the experimental results of  $\kappa_{lat} + \kappa_b$  and the calculated ones, before  $\kappa_{lat} + \kappa_b$  are governed by  $\kappa_b$ . Then, we could extrapolate the values of  $\kappa_{lat}$  at relatively high temperature, based on the above expressions. Finally,  $\kappa_b$  can be obtained through subtracting the calculated  $\kappa_{lat}$  from  $\kappa_{lat} + \kappa_b$  (Fig. S7c and S7f).



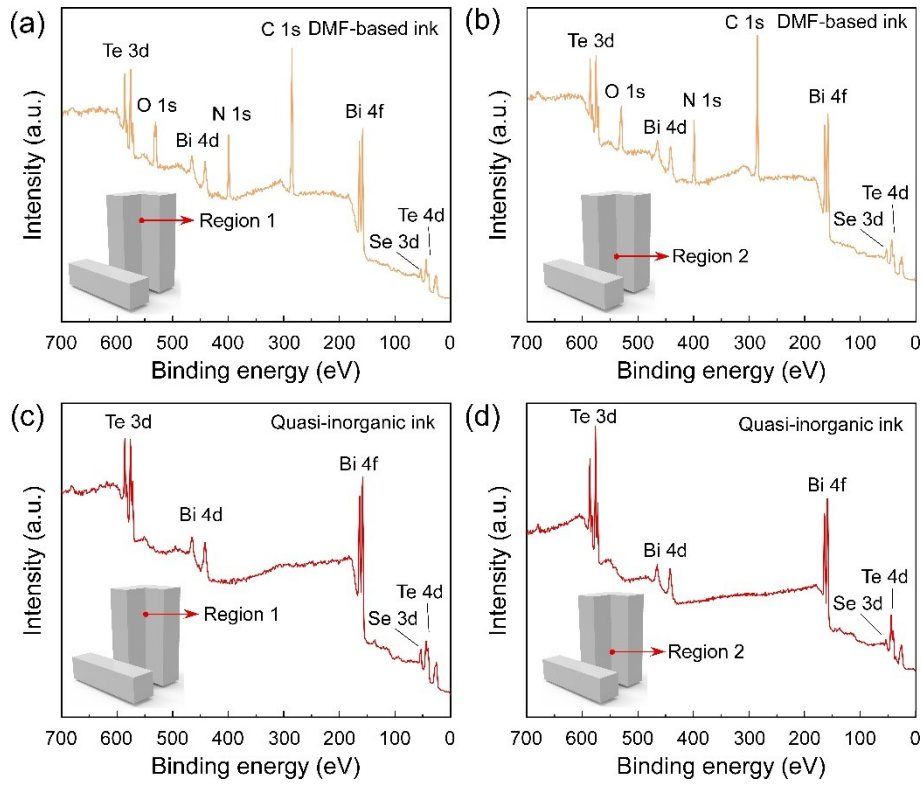
**Fig. S1.** Stability of  $\text{Bi}_2\text{Te}_3$ -based TE inks. Photographs of inks without (a) and with (b) PAA-PEI binders. (c) Complex viscosity corresponding to TE inks with binders (b). Photographs of inks after 5-days-settlement without (d) and with (e) PAA-PEI binders. (f) Complex viscosity corresponding to TE inks with binders (e).



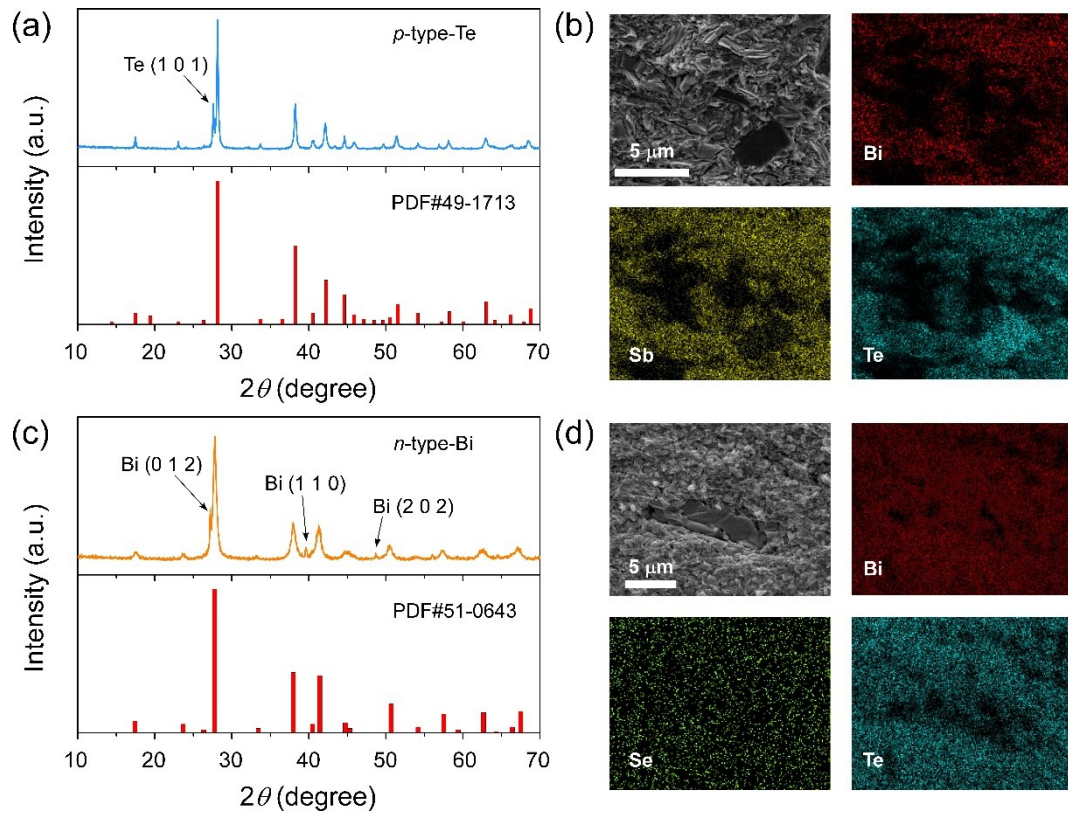
**Fig. S2.** Loss tangent  $\tan\delta$  curves of TE inks containing 81wt% particles loading with different binders content (a) 0.2wt%, (b) 0.6wt%, (c) 1.0wt%, (d) 1.2wt%. Loss tangent  $\tan\delta$  curves of TE inks containing 1.0wt% binders with various particles loading (e) 70wt%, (f) 74wt%, (g) 81wt%, (h) 85wt%.



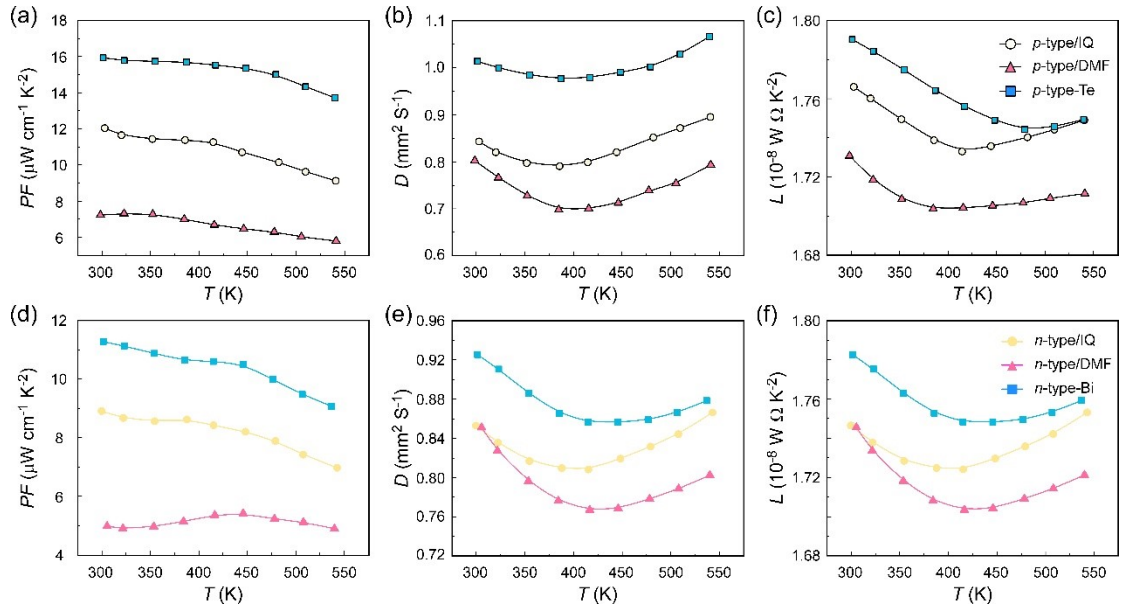
**Fig. S3.** (a) Complex viscosity and (b) storage modulus curves of 1.0wt% binders TE inks with various particle loadings.



**Fig. S4.** XPS spectrums of (a) Region 1 and (b) Region 2 selected in *n*-type sample printed by DMF-based inks. XPS spectrums of (c) Region 1 and (d) Region 2 selected in *n*-type sample printed by quai-inorganic inks. The above peaks are indexed to Te 3d, Te 4d, Bi 4d, Bi 4f, Se 3d, C 1s, O 1s, and N 1s, respectively [3, 4].

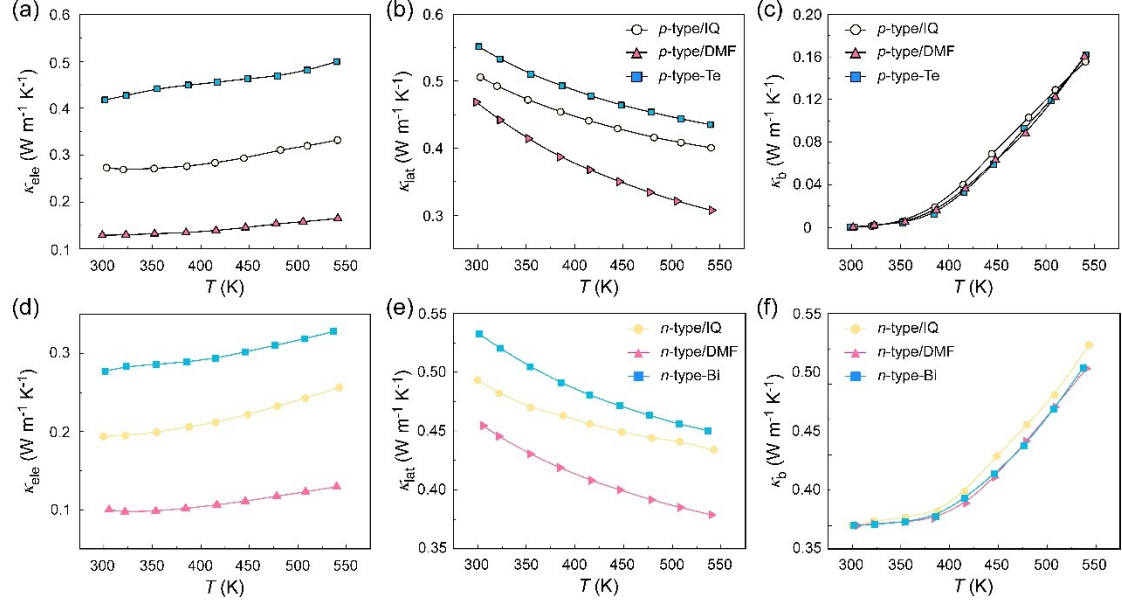


**Fig. S5.** (a) XRD patterns for 3D-printed *p*-type-Te. (b) Fracture surface morphology and corresponding energy-dispersive spectroscopy (EDS) mapping for 3D-printed *p*-type-Te. (c) XRD patterns for 3D-printed *n*-type-Bi. (d) Fracture surface morphology and corresponding EDS mapping for 3D-printed *n*-type-Bi.

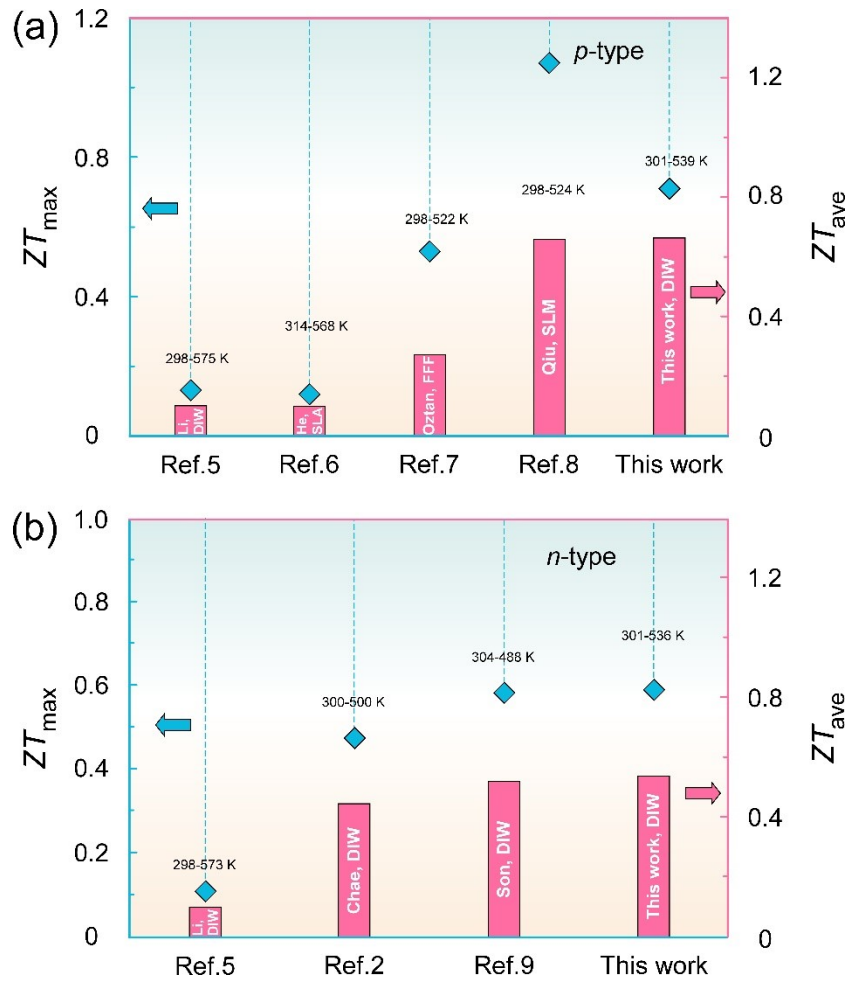


**Fig. S6.** Temperature-dependent (a) power factor  $PF$ , (b) thermal diffusivities  $D$ , (c) Lorenz numbers  $L$  of 3D-printed  $p$ -type samples. Temperature-dependent (d) power factor  $PF$ , (e) thermal diffusivities  $D$ , (f) Lorenz numbers  $L$  of 3D-printed  $n$ -type samples .

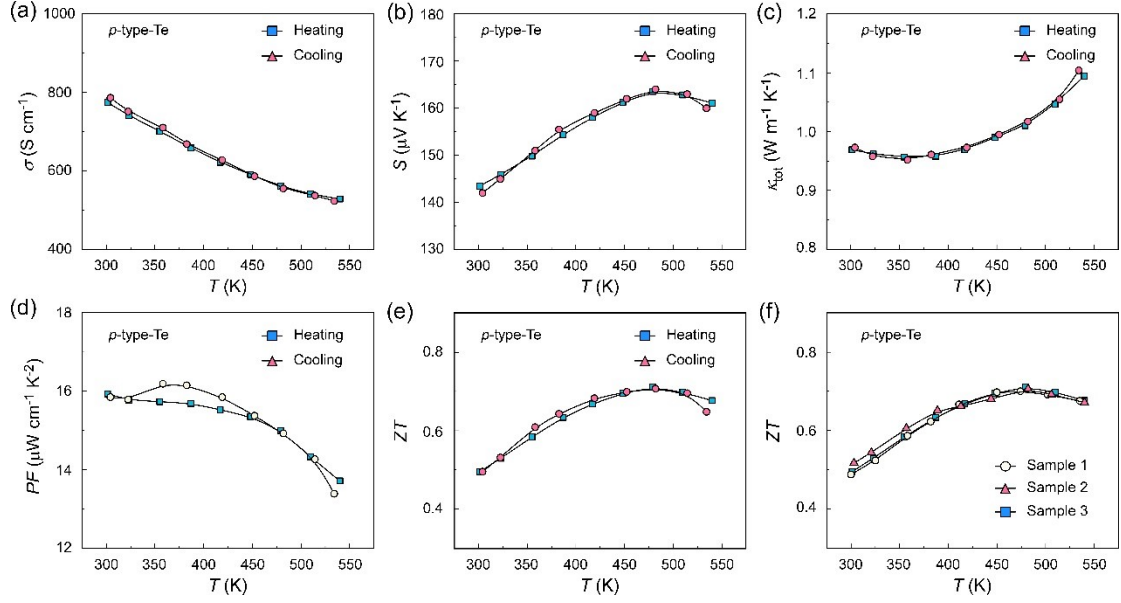




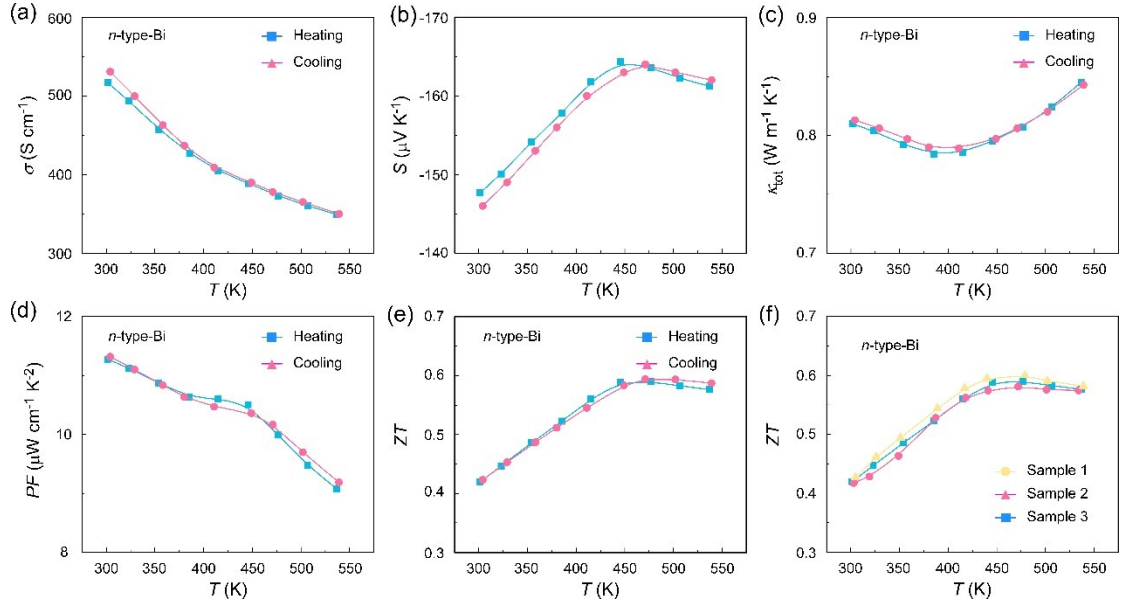
**Fig. S7.** Temperature-dependent (a) electrical thermal conductivities  $\kappa_{\text{ele}}$ , (b) lattice thermal conductivities  $\kappa_{\text{lat}}$ , (c) bipolar thermal conductivities  $\kappa_{\text{lat}}$  of 3D-printed  $p$ -type samples. Temperature-dependent (d) electrical thermal conductivities  $\kappa_{\text{ele}}$ , (e) lattice thermal conductivities  $\kappa_{\text{lat}}$ , (f) bipolar thermal conductivities  $\kappa_{\text{b}}$  of 3D-printed  $n$ -type samples. The calculation details of bipolar thermal conductivities  $\kappa_{\text{b}}$  had been reported in 3D-printed and bulk  $\text{Bi}_2\text{Te}_3$ -based materials [1].



**Fig. S8.** Comparison of  $ZT$  maximum values ( $ZT_{max}$ ) and average  $ZT$  values ( $ZT_{ave}$ ) with previous reported (a)  $p$ -type [5-8], and (b)  $n$ -type [2, 5, 9] 3D-printed Bi<sub>2</sub>Te<sub>3</sub>-based thermoelectric materials fabricated by DIW, sterolithography apparatus (SLA), fused filament fabrication (FFF), and selective laser melting (SLM).



**Fig. S9.** Stability evaluation of the high-performance 3D-printed *p*-type-Te samples from heating to cooling cycles. (a) Electrical conductivity  $\sigma$ ; (b) Seebeck coefficient  $S$ ; (c) total thermal conductivity  $\kappa_{\text{tot}}$ ; (d) power factor  $PF$ ; (e)  $ZT$  values; (f) reproducibility of  $ZT$  values for three different *p*-type-Te samples printed independently.



**Fig. S10.** Stability evaluation of the high-performance 3D-printed *n*-type-Bi samples from heating to cooling cycles. (a) Electrical conductivity  $\sigma$ ; (b) Seebeck coefficient  $S$ ; (c) total thermal conductivity  $\kappa_{\text{tot}}$ ; (d) power factor  $PF$ ; (e)  $ZT$  values; (f) reproducibility of  $ZT$  values for three different *n*-type-Bi samples printed independently.

Table S1. The calculated particle loading of TE inks, density, and relative density of *p*-type/IQ, *n*-type/IQ, *p*-type/DMF, *n*-type/DMF, *p*-type/Te, *n*-type/Bi.

	Particle loading	Density (g/cm <sup>3</sup> )	Relative density
<i>p</i> -type/IQ	65.5wt%	2.44	35.9%
	70.4wt%	2.86	42.1%
	74.0wt%	3.70	54.4%
	81.1wt%	5.21	76.6%
	85.1wt%	5.42	79.7%
<i>n</i> -type/IQ	65.5wt%	2.36	30.7%
	70.4wt%	2.98	38.7%
	74.0wt%	3.57	46.4%
	81.1wt%	4.92	63.9%
	85.1wt%	5.08	66.1%
<i>p</i> -type/DMF	81.1wt%	4.37	64.2%
<i>n</i> -type/DMF	81.1wt%	4.11	53.4%
<i>p</i> -type/Te	81.1wt%	5.61	82.5%
<i>n</i> -type/Bi	81.1wt%	5.52	71.8%

Table S2. The output performance of the TE devices.

Materials	<i>p</i> : segmented BiSbTe	<i>p</i> : Bi <sub>0.5</sub> Sb <sub>1.5</sub> Te <sub>3</sub>	<i>p</i> : Bi <sub>0.4</sub> Sb <sub>1.6</sub> Te <sub>3</sub>	<i>p</i> : Bi <sub>0.5</sub> Sb <sub>1.5</sub> Te <sub>3.0</sub>
		<i>n</i> : Bi <sub>2</sub> Te <sub>3</sub>	<i>n</i> : Bi <sub>2</sub> Sb <sub>2.7</sub> Se <sub>0.3</sub>	<i>n</i> : Bi <sub>2.0</sub> Te <sub>2.7</sub> Se <sub>0.3</sub>
Device structure	Tri-block	Annular	Half annular	Half annular
Method	DIW	DIW	DIW	DIW
Number of legs	1	5	3	3
$\Delta T$ (K)	236.1	54.6	39.2	55.6
$V_{OC}$ (mV)	53	60.8	27	40.61
$V_{OC}$ per leg (mV)	53	12.16	9	13.53
$P_{max}$ ( $\mu$ W)	260	678	1420	380
$P_{max}$ per leg ( $\mu$ W)	260	135.6	473.3	126.6
Reference	[1]	[5]	[9]	This work

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